CRYSTALLOGRAPHERS

The biographical data include full name and title, address, year of birth, highest degree, field of study, university and year of highest degree, present position, telephone number and major scientific interests. There is also a comprehensive name index.

The General Editor of the Directory is Dr S. C. Abrahams and the Associate Editor is Dr A. L. Bednowitz. Crystallographers have completed Data Input Forms and have submitted them to the national Sub-Editors. The Directory has been produced by a computer-controlled experimental printer from punched cards or magnetic tapes prepared by the Sub-Editors. All National Committees for Crystallography, and also all Sub-Editors for countries not represented in the Union but included in the Directory, have been given the opportunity to compile block orders for copies at a specially reduced price. These orders had to be submitted before the Directory was printed, but many countries took this opportunity to secure low-priced copies of the Directory for the personal use of their crystallographers.

Notes and News

Announcements and other items of crystallographic interest will be published under this heading at the discretion of the Editorial Board. The notes (in duplicate) should be sent to the Executive Secretary of the International Union of Crystallography (J. N. King, International Union of Crystallography, 13 White Friars, Chester CH1 1N2, England).

Crystal Growth Award of the American Association for Crystal Growth

The establishment of a new award for "outstanding contributions to the field of crystal growth" was announced at Boston, Massachusetts, on 21 July 1977 by the American Association for Crystal Growth (AACG), at the Fifth International Conference on Crystal Growth. The Crystal Growth Award of the AACG, supported by the Union Carbide Corporation, will consist of a certificate citing the contributions for which the Award is given, a medal and an honorarium of $3000.

The Award, to be presented triennially at the AACG's national meetings, will be given first in 1978. It may be shared by more than one individual, and the recipient(s) will be invited to deliver a lecture during the course of the ceremony. The basic criterion for eligibility is outstanding contributions to the field of crystal growth, through technical achievements, publications and presentations, and their impact on science and technology in crystal growth worldwide. Those selected need not be citizens of the United States. Nominations, together with concise supporting documentation, should be for-